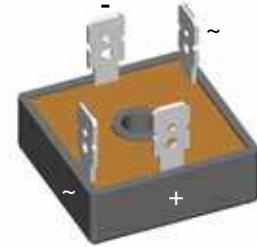
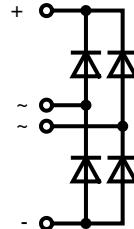


# Single Phase Rectifier Bridge

**I<sub>dAV</sub> = 30 A**  
**V<sub>RRM</sub> = 800-1800 V**

V <sub>RSM</sub> V	V <sub>RRM</sub> V	Type
900	800	VBO 36-08N08
1300	1200	VBO 36-12N08
1700	1600	VBO 36-16N08
1900	1800	VBO 36-18N08



RU

Symbol	Conditions	Maximum Ratings		
I <sub>dAV</sub>	T <sub>C</sub> = 85°C, module	25	A	
I <sub>dAVM</sub>	T <sub>C</sub> = 62°C, module	30	A	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz)	550	A	
	V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	600	A	
	T <sub>VJ</sub> = T <sub>VJM</sub> ; t = 10 ms (50 Hz)	500	A	
	V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	550	A	
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz)	1520	A <sup>2</sup> s	
	V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	1520	A <sup>2</sup> s	
	T <sub>VJ</sub> = T <sub>VJM</sub> ; t = 10 ms (50 Hz)	1250	A <sup>2</sup> s	
	V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	1250	A <sup>2</sup> s	
T <sub>VJ</sub>		-40...+150	°C	
T <sub>VJM</sub>		150	°C	
T <sub>stg</sub>		-40...+150	°C	
V <sub>ISOL</sub>	50/60 Hz, RMS t = 1 min	2500	V~	
	I <sub>ISOL</sub> ≤ 1 mA t = 1 s	3000	V~	
M <sub>d</sub>	Mounting torque (M5) (10-32 UNF)	2 ±10% 18 ±10%	Nm lb.in.	
Weight	Typ.	22	g	

Symbol	Conditions	Characteristic Values		
I <sub>R</sub>	V <sub>R</sub> = V <sub>RRM</sub> T <sub>VJ</sub> = 25°C	0.3	mA	
	T <sub>VJ</sub> = T <sub>VJM</sub>	2.0	mA	
V <sub>F</sub>	I <sub>F</sub> = 150 A T <sub>VJ</sub> = 25°C	1.7	V	
V <sub>TO</sub>	For power-loss calculations only	0.8	V	
r <sub>t</sub>		5.8	mΩ	
R <sub>thJC</sub>	per diode; 120° el.	6.20	K/W	
	per module	1.55	K/W	
R <sub>thJH</sub>	per diode; 120° el.	7.40	K/W	
	per module	1.85	K/W	
d <sub>s</sub>	Creeping distance on surface	12.7	mm	
d <sub>A</sub>	Creepage distance in air	9.4	mm	
a	Max. allowable acceleration	50	m/s <sup>2</sup>	

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

IXYS reserves the right to change limits, test conditions and dimensions.

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## Features

- Package with 1/4" fast-on terminals
- Isolation voltage 3000 V~
- Planar passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 72873

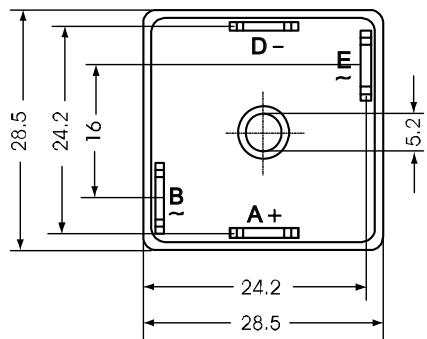
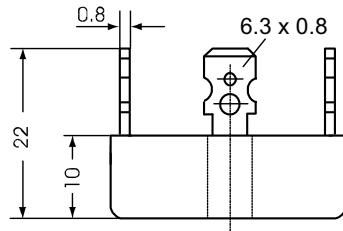
## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature & power cycling

## Dimensions in mm (1 mm = 0.0394")



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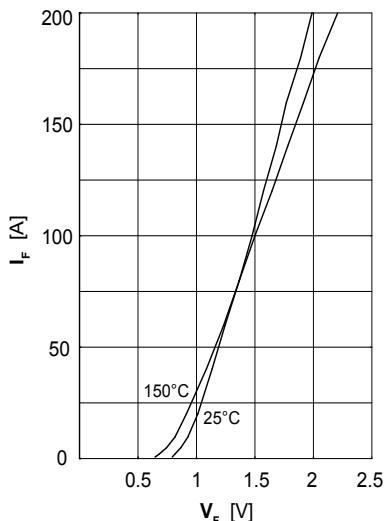


Fig. 1 Forward current versus voltage drop per diode

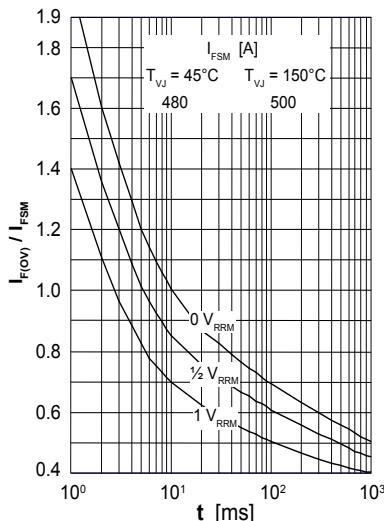


Fig. 2 Surge overload current per diode  
 $I_{FSM}$ : crest value, t: duration

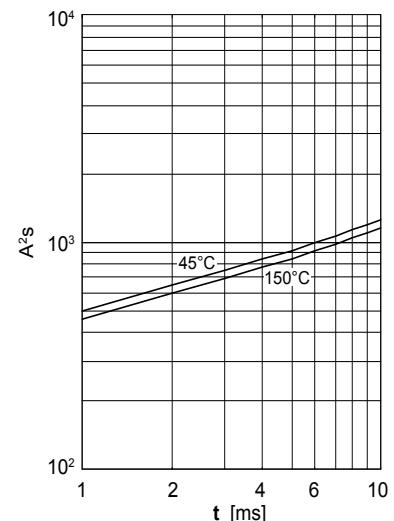


Fig. 3  $I^2t$  versus time (1-10 ms)  
per diode or thyristor

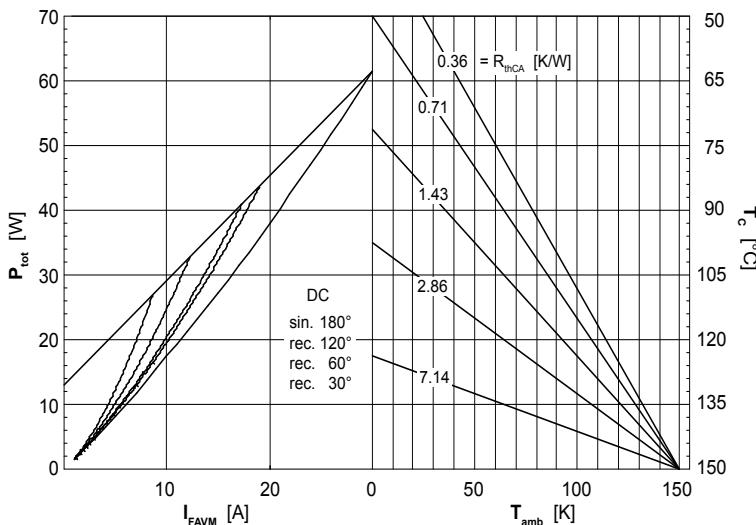


Fig. 4 Power dissipation vs. direct output current and ambient temperature

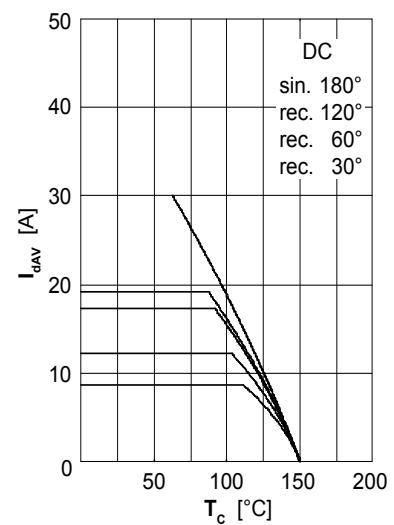


Fig. 5 Maximum forward current at case temperature

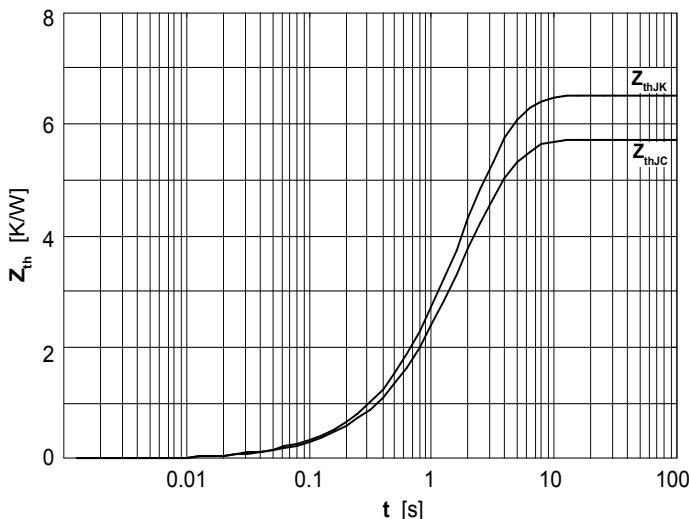


Fig. 6 Transient thermal impedance per diode or thyristor, calculated

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